

DIODE(THREE PHASES BRIDGE TYPE)**DF30AA120/160**

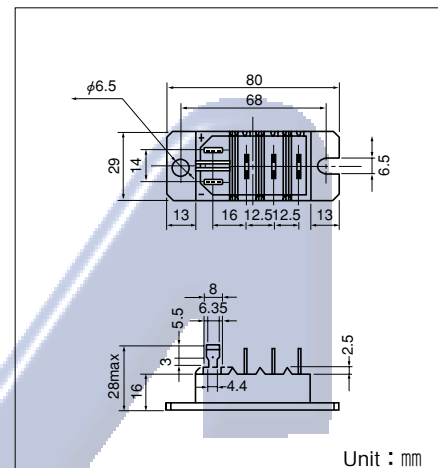
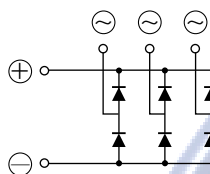
UL:E76102(M)

Power Diode Module **DF30AA** is designed for three phase full wave rectification, which has six diodes connected in a three phase bridge configuration. The mounting base of the module is electrically isolated from semiconductor elements for simple heatsink construction output DC current is 30Amp ($T_c=117^{\circ}\text{C}$) Repetitive peak reverse voltage is up to 1,600V.

- $T_{j\text{Max}}=150^{\circ}\text{C}$
- Isolated Mounting Base
- High reliability by unique glass passivation
- Easy Assemble by the #250 terminal Tab

(Applications)

AC. DC Motor Drive/AVR/Switching
—for three phase rectification

**Maximum Ratings**(T_j=25°C unless otherwise specified)

Symbol	Item	Ratings		Unit
		DF30AA120	DF30AA160	
V _{RRM}	Repetitive Peak Reverse Voltage	1200	1600	V
V _{RSM}	Non-Repetitive Peak Reverse Voltage	1300	1700	V

Symbol	Item		Conditions	Ratings	Unit
I _D	Output current (D.C.)		Three phase. full wave. T _c =117°C	30	A
I _{FSM}	Surge Forward Current		1 cycle, 50/60Hz, peak value, non-repetitive	270/300	A
T _j	Junction Temperature			-40 to +150	°C
T _{stg}	Storage Temperature			-40 to +125	°C
Viso	Isolation Breakdown Voltage (R.M.S.)		Main Terminal to case 1minute	2500	V
Mounting Torque	Mounting (M6)		Recommended Value 2.5-3.9 (25-40)	4.7 (48)	N·m
	Terminal	Tub Terminal # 250		—	(kgf·cm)
Mass			Typical Value	90	g

Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
I _{RRM}	Repetitive Peak Reverse Current, max.	T _j =150°C at V _{RRM}	3.0	mA
V _{FM}	Forward Voltage Drop, max.	I _{FM} =30A, T _j =25°C Inst. measurement	1.3	V
R _{th(j-c)}	Thermal Impedance, max.	Junction to case	0.42	°C/W